Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

3.000 inches

Overall Height:

0.650 inches

Overall Width:

1.000 inches

Mounting Facility Quantity:

2

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.112 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

1200.0 reverse voltage, peak

Current Rating Per Characteristic:

2.00 amperes forward current, average absolute

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Thread Series Designator:

Unc

Terminal Type And Quantity:

2 threaded hole

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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